



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

**SURFACE MOUNT
NPN Digital Silicon Transistor**

VOLTAGE 50 Volts CURRENT 100 mAmpere

CHIMH3GP

APPLICATION

* Switching circuit, Inverter, Interface circuit, Driver circuit.

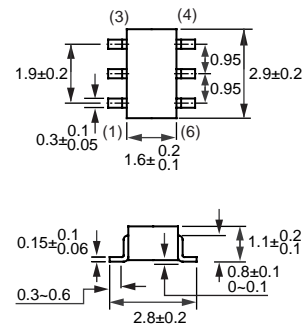
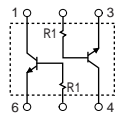
FEATURE

- * Small surface mounting type. (SC-74/SOT-457)
- * High current gain.
- * Suitable for high packing density.
- * Low collector-emitter saturation.
- * High saturation current capability.
- * Two CHDTC143T chips in one package.
- * Built in bias resistor(R1=4.7kΩ, Typ.)



SC-74/SOT-457

CIRCUIT



Dimensions in millimeters

SC-74/SOT-457

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Vcbo	Collector-Base voltage		50	V
Vceo	Collector-Emitter voltage		50	V
Vebo	Emitter-Base voltage		5	V
Ic(Max.)	Collector current		100	mA
Pd	Power dissipation	Tamb ≤ 25 °C, Note 1	300	mW
Tstg	Storage temperature		-55 +150	°C
Tj	Junction temperature		150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC (CHIMH3GP)

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BVCBO	Collector-Base breakdown voltage	$I_C=50\mu\text{A}$	50.0	–	–	V
BVCEO	Collector-Emitter breakdown voltage	$I_C=1\text{mA}$	50.0	–	–	V
BVEBO	Emitter-Base breakdown voltage	$I_E=50\mu\text{A}$	5.0	–	–	V
VCE(sat)	Collector-Emitter Saturation voltage	$I_C=5\text{mA}; I_B=0.25\text{mA}$	–	–	0.3	V
ICBO	Collector-Base current	$V_{CB}=50\text{V}$	–	–	0.5	μA
IEBO	Emitter-Base current	$V_{EB}=4\text{V}$	–	–	0.5	μA
hFE	DC current gain	$I_C=1\text{mA}; V_{CE}=5.0\text{V}$	100	250	600	
R ₁	Input resistor		3.29	4.7	6.11	K Ω
f _T	Transition frequency	$I_E=-5\text{mA}, V_{CE}=10.0\text{V}$ $f=100\text{MHz}$	–	250	–	MHz

Note

1. Pulse test: $t_p \leq 300\mu\text{s}; \delta \leq 0.02$.

RATING CHARACTERISTIC CURVES (CHIMH3GP)

Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

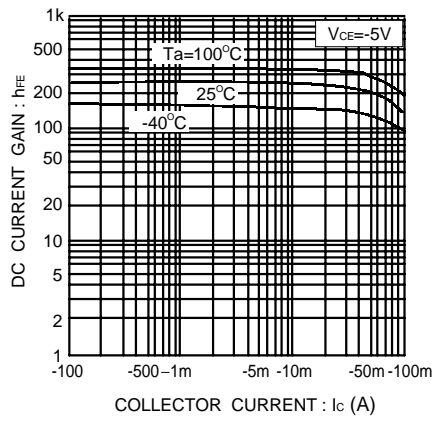


Fig.2 Collector-emitter saturation voltage vs. collector current

